

2SJ451 Silicon P Channel MOS FET

REJ03G0864-0400 Rev.4.00 Sep 07, 2007

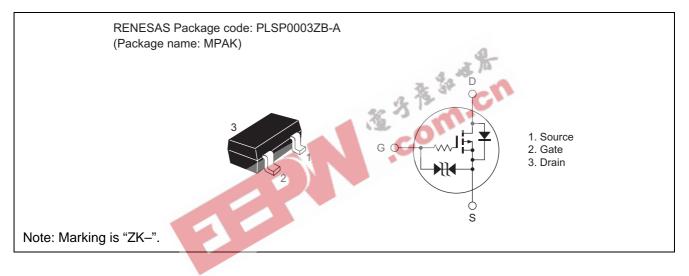
Description

Low frequency power switching

Features

- Low on-resistance.
- Low drive power
- 2.5 V gate drive device.
- Small package (MPAK).

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	-20	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	-0.2	А
Drain peak current	I _{D (pulse)} Note 1	-0.4	А
Channel dissipation	Pch	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

Electrical Characteristics

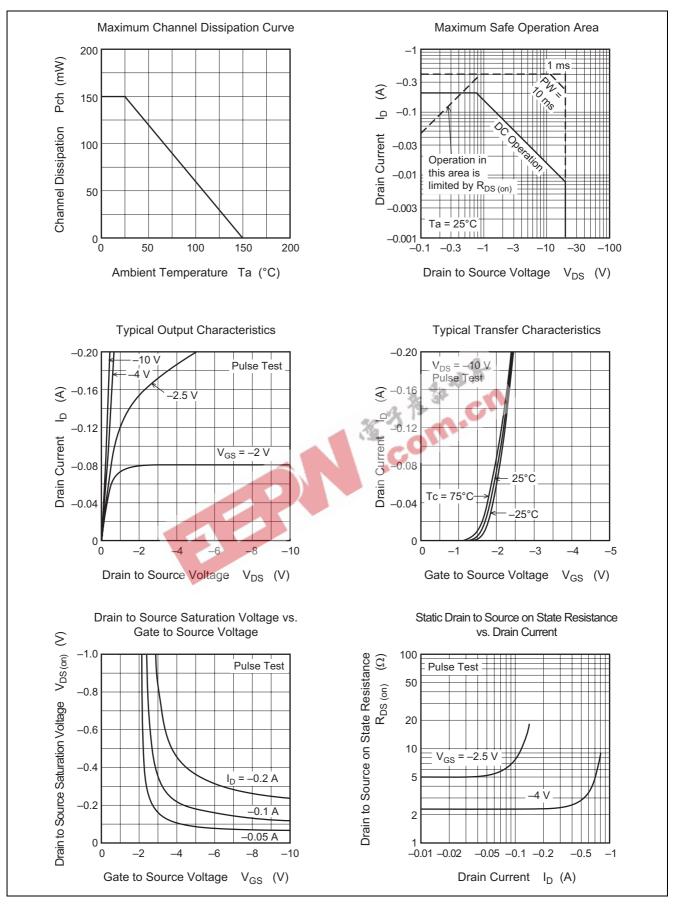
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V (BR) DSS	-20	_		V	$I_D = -100 \ \mu A, \ V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	±20	_	—	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-1.0	μΑ	$V_{DS} = -16 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±2.0	μΑ	$V_{GS} = \pm 16 V, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	-0.5	_	-1.5	V	$I_D = -10 \ \mu A, \ V_{DS} = -5 \ V$
Static drain to source on state resistance	R _{DS (on) 1}	—	2.3	3.5	Ω	$I_D = -100 \text{ mA}, V_{GS} = -4 \text{ V}^{Note 2}$
	R _{DS} (on) 2	—	5.0	9.0	Ω	$I_D = -40$ mA, $V_{GS} = -2.5$ V ^{Note 2}
Forward transfer admittance	y _{fs}	0.13	0.23		S	$I_D = -100 \text{ mA}, V_{DS} = -10 \text{ V}^{Note 2}$
Input capacitance	Ciss	—	2.4	—	pF	$V_{DS} = -10 V$
Output capacitance	Coss	—	31	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	0.6	—	pF	f = 1 MHz
Turn-on delay time	t _{d (on)}	—	170	—	ns	$I_{\rm D} = -0.1 {\rm A}$
Rise time	tr		680		ns	$V_{GS} = -10 \text{ V}$
Turn-off delay time	t _{d (off)}		3.0		μs	R _L = 100 Ω
Fall time	t _f		2.8		μs	

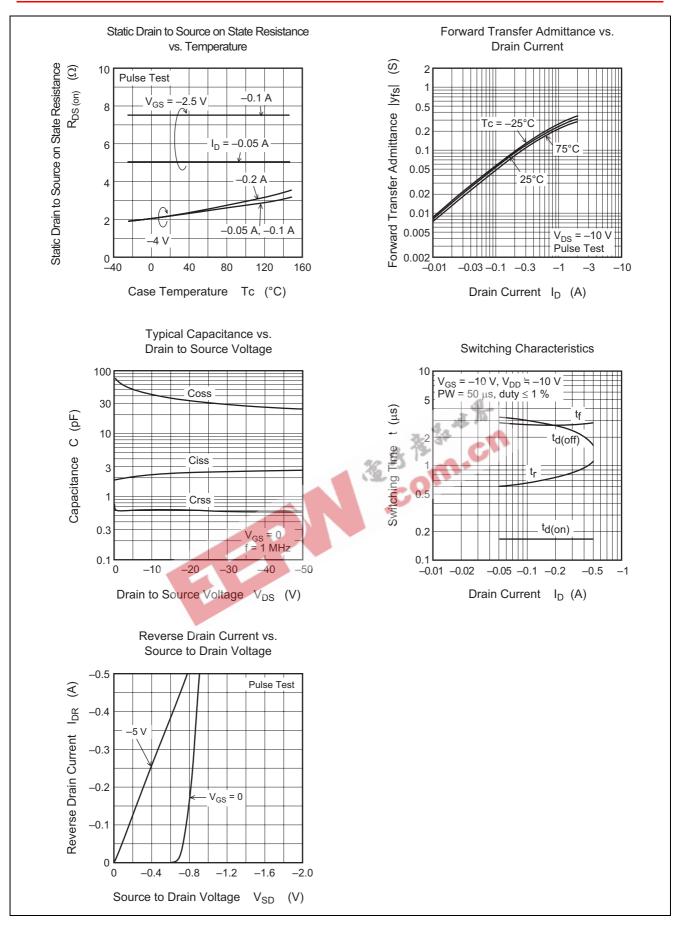
Note: 2. Pulse test



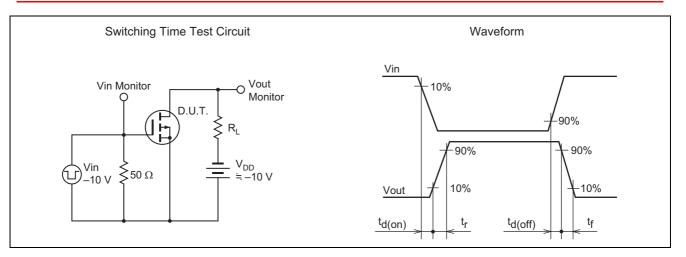
Main Characteristics



RENESAS

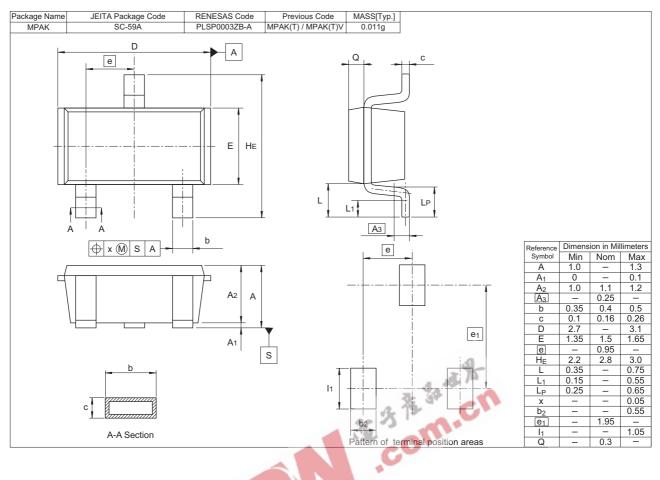


RENESAS





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SJ451ZK-TL-E	3000 pcs	Taping
2SJ451ZK-TR-E	3000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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